

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

P-Channel Silicon MOSFET

# SCH1335 — General-Purpose Switching Device Applications

#### **Features**

- 1.8V drive
- · Halogen free compliance

#### **Specifications**

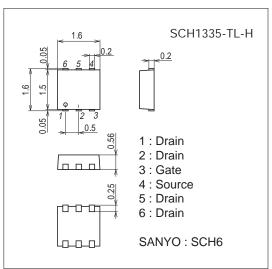
#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		-12	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±10	V
Drain Current (DC)	ID		-2.5	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-10	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm <sup>2</sup> x0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

This product is designed to "ESD immunity < 200V\*", so please take care when handling.

#### **Package Dimensions**

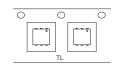
unit : mm (typ) 7028-002



#### **Product & Package Information**

Package : SCH6
 JEITA, JEDEC : SOT-563
 Minimum Packing Quantity : 5,000 pcs./reel

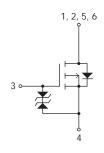
#### Packing Type : TL



# Marking



#### **Electrical Connection**



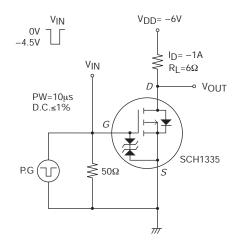
<sup>\*</sup> Machine Model

#### SCH1335

#### Electrical Characteristics at Ta=25°C

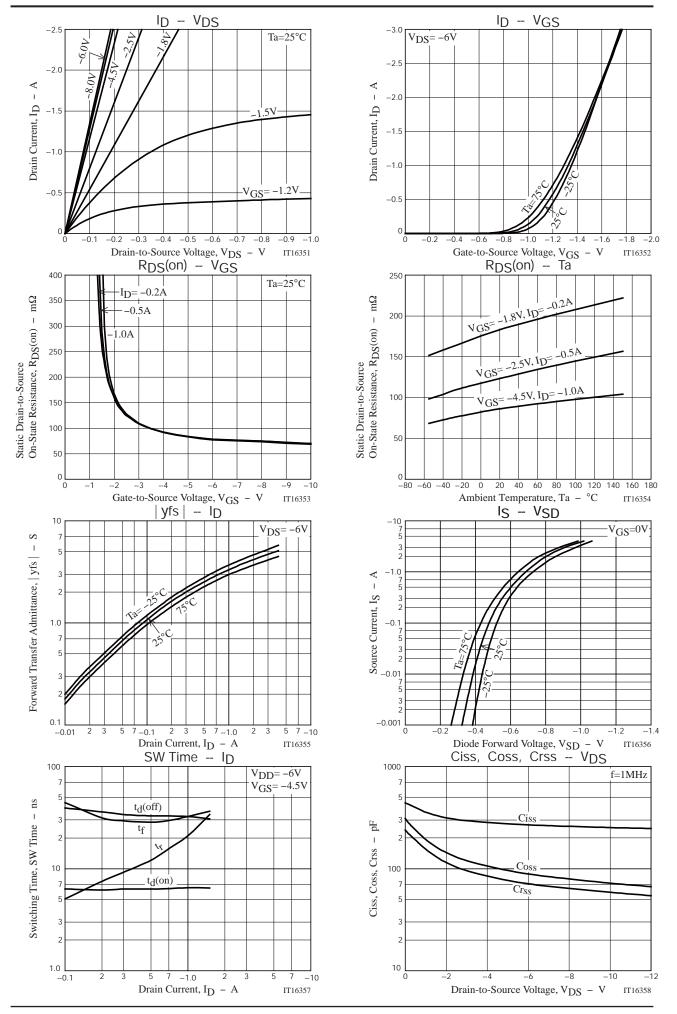
Parameter	Cump b ol	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	UIIII	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-12			V	
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-12V, V <sub>GS</sub> =0V			-10	μΑ	
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μΑ	
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =-6V, I <sub>D</sub> =-1mA	-0.4		-1.3	V	
Forward Transfer Admittance	yfs	V <sub>D</sub> S=-6V, I <sub>D</sub> =-1A		3.3		S	
	R <sub>DS</sub> (on)1	I <sub>D</sub> =-1A, V <sub>G</sub> S=-4.5V		86	112	mΩ	
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)2	I <sub>D</sub> =-0.5A, V <sub>G</sub> S=-2.5V		125	175	mΩ	
	R <sub>DS</sub> (on)3	I <sub>D</sub> =-0.2A, V <sub>G</sub> S=-1.8V			285	mΩ	
Input Capacitance	Ciss			270		pF	
Output Capacitance	Coss	V <sub>DS</sub> =-6V, f=1MHz		90		pF	
Reverse Transfer Capacitance	Crss			72		pF	
Turn-ON Delay Time	t <sub>d</sub> (on)			6.5		ns	
Rise Time	t <sub>r</sub>	See specified Test Circuit.		21		ns	
Turn-OFF Delay Time	t <sub>d</sub> (off)			33		ns	
Fall Time	tf			33		ns	
Total Gate Charge	Qg			3.1		nC	
Gate-to-Source Charge	Qgs	$V_{DS}=-6V$ , $V_{GS}=-4.5V$ , $I_{D}=-2.5A$		0.7		nC	
Gate-to-Drain "Miller" Charge	Qgd	_		0.9		nC	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-2.5A, V <sub>GS</sub> =0V		-0.84	-1.2	V	

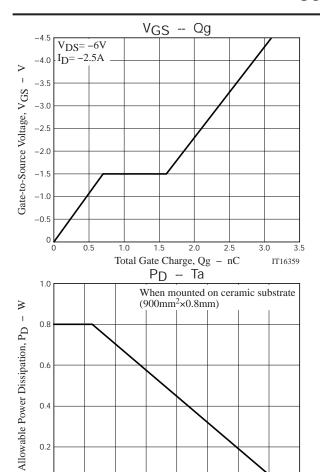
## Switching Time Test Circuit



#### **Ordering Information**

Device	Package	Shipping	memo	
SCH1335-TL-H	SCH6	5,000pcs./reel	Pb Free and Halogen Free	





0.2

0 L

20

60

80

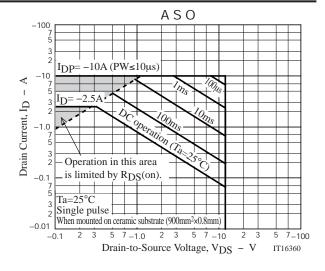
Ambient Temperature, Ta - °C

100

140

160

IT16361

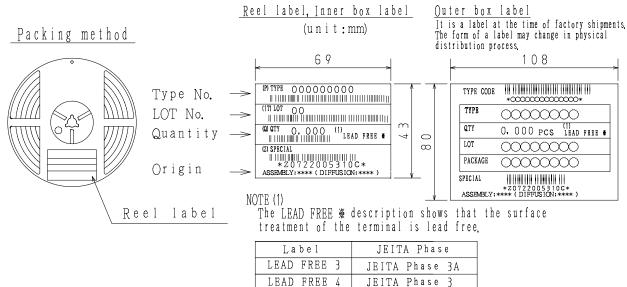


#### **Taping Specification**

#### SCH1335-TL-H

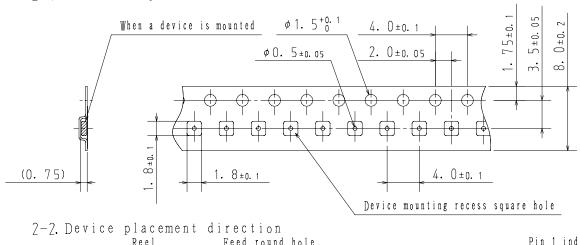
#### 1. Packing Format

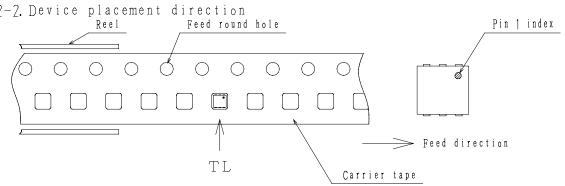
Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing format		
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
SCH6	SCH6	5,000	25, 000	150,000	5 reels contained	6 inner boxes contained	
					Dimensions:mm (external)	Dimensions:mm (external)	
					183×72×185	440×195×210	



#### 2. Taping configuration

#### 2-1. Carrier tape size (unit:mm)

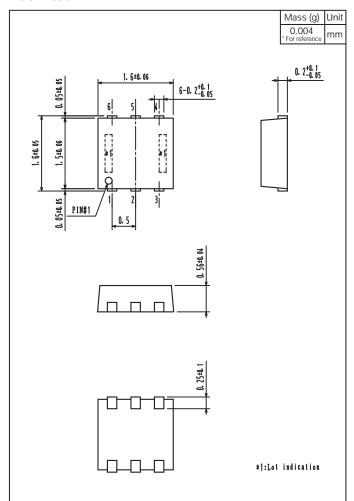




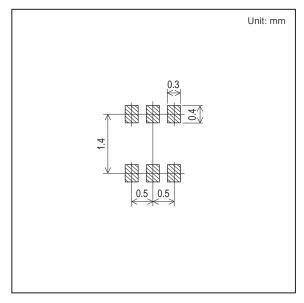
Those with pin 1 index on the feed hole side·····TL

# **Outline Drawing**

SCH1335-TL-H



### Land Pattern Example



Note on usage: Since the SCH1335 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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